

Practitioner's Docket No.: 811\_107

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of: Makoto IWAI, Katsuhiro IMAI and Minoru IMAEDA

Serial No.: 10/594,846

Group Art Unit: 1792

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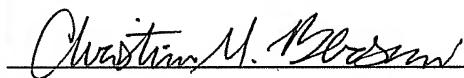
Conf. No.: 3664

For: GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD  
AND GALLIUM NITRIDE SINGLE CRYSTAL

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**CERTIFICATION OF EFS  
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I hereby certify that this paper is being transmitted via EFS to the Patent  
and Trademark Office on December 17, 2009.



Christina M. Bersani

**AMENDMENT**

Sir:

In response to the Office Action mailed September 17, 2009, please amend the  
above-identified application as follows:

**Amendments to the Specification** are shown on page 2 of this paper.

**Amendments to the Claims** begin on page 3 of this paper.

**Remarks/Arguments** begin on page 5 of this paper.